



**THE DATASHEET OF
ADG3257BRQZ-REEL7**





FEATURES

- 100 ps propagation delay through the switch
- 2 Ω switches connect inputs to outputs
- Data rates up to 933 Mbps
- Single 3.3 V/5 V supply operation
- Level translation operation
- Ultralow quiescent supply current (1 nA typical)
- 3.5 ns switching
- Switches remain in the off state when power is off
- Standard 3257 type pinout

APPLICATIONS

- Bus switching
- Bus isolation
- Level translation
- Memory switching/interleaving

GENERAL DESCRIPTION

The ADG3257 is a CMOS bus switch comprised of four 2:1 multiplexers/demultiplexers with high impedance outputs. The device is manufactured on a CMOS process. This provides low power dissipation yet high switching speed and very low on resistance, allowing the inputs to be connected to the outputs without adding propagation delay or generating additional ground bounce noise.

The ADG3257 operates from a single 3.3 V/5 V supply. The control logic for each switch is shown in Table 1. These switches are bidirectional when on. In the off state, signal levels are blocked up to the supplies. When the power supply is off, the switches remain in the off state, isolating Port A and Port B.

This bus switch is suited to both switching and level translation applications. It can be used in applications requiring level translation from 3.3 V to 2.5 V when powered from 3.3 V. Additionally, with a diode connected in series with 5 V V_{DD} , the ADG3257 may also be used in applications requiring 5 V to 3.3 V level translation.

Table 1. Truth Table

BE	S	Function
H	X	Disable
L	L	A = B ₁
L	H	A = B ₂

FUNCTIONAL BLOCK DIAGRAM

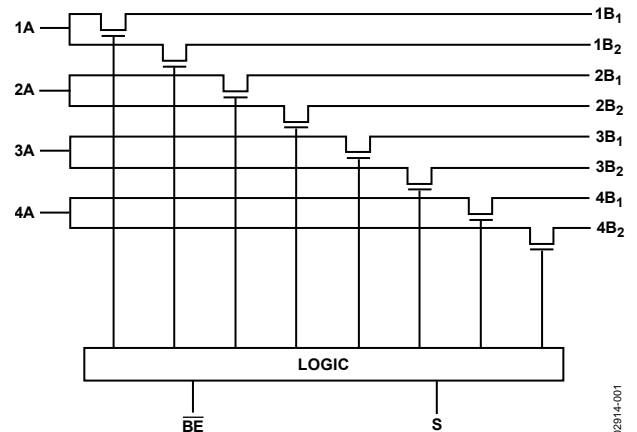


Figure 1.

PRODUCT HIGHLIGHTS

- 0.1 ns propagation delay through switch.
- 2 Ω switches connect inputs to outputs.
- Bidirectional operation.
- Ultralow power dissipation.
- 16-lead QSOP package.

Rev. E

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REVISION HISTORY**03/08—Rev. D to Rev. E**

Updated Format.....	Universal
Changes to Features.....	1
Changes to General Description	1
Changes to Absolute Maximum Ratings	5
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11/04—Rev. C to Rev. D

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04/03—Rev. A to Rev. B

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06/02—Rev. 0 to Rev. A

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SPECIFICATIONS

$V_{CC} = 5.0\text{ V} \pm 10\%$, $GND = 0\text{ V}$. All specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 2.

Parameter ¹	Symbol	Conditions ²	B Version			Unit
			Min	Typ ³	Max	
DC ELECTRICAL CHARACTERISTICS						
Input High Voltage	V_{INH}		2.4			V
Input Low Voltage	V_{INL}		-0.3		+0.8	V
Input Leakage Current	I_I	$0 \leq V_{IN} \leq 5.5\text{ V}$		± 0.01	± 1	μA
Off State Leakage Current	I_{OZ}	$0 \leq A, B \leq V_{CC}$		± 0.01	± 1	μA
On State Leakage Current	I_{OZ}	$0 \leq A, B \leq V_{CC}$		± 0.01	± 1	μA
Maximum Pass Voltage ⁴	V_P	$V_{IN} = V_{CC} = 5\text{ V}$, $I_O = -5\ \mu\text{A}$	3.9	4.2	4.4	V
CAPACITANCE⁴						
A Port Off Capacitance	$C_{A\ OFF}$	$f = 1\text{ MHz}$		7		pF
B Port Off Capacitance	$C_{B\ OFF}$	$f = 1\text{ MHz}$		5		pF
A, B Port On Capacitance	$C_{A, C_B\ ON}$	$f = 1\text{ MHz}$		11		pF
Control Input Capacitance	C_{IN}	$f = 1\text{ MHz}$		4		pF
SWITCHING CHARACTERISTICS⁴						
Propagation Delay A to B or B to A, t_{PD}	t_{PHL}, t_{PLH} ⁵	$V_A = 0\text{ V}$, $C_L = 50\text{ pF}$			0.10	ns
Propagation Delay Matching ⁶		$V_A = 0\text{ V}$, $C_L = 50\text{ pF}$		0.0075	0.035	ns
Bus Enable Time \overline{BE} to A or B	t_{PZH}, t_{PZL}	$C_L = 50\text{ pF}$, $R_L = 500\ \Omega$	1	5	7.5	ns
Bus Disable Time \overline{BE} to A or B	t_{PHZ}, t_{PLZ}	$C_L = 50\text{ pF}$, $R_L = 500\ \Omega$	1	3.5	7	ns
Bus Select Time S to A or B						
Enable	t_{SEL_EN}	$C_L = 50\text{ pF}$, $R_L = 500\ \Omega$		8	12	ns
Disable	t_{SEL_DIS}	$C_L = 50\text{ pF}$, $R_L = 500\ \Omega$		5	8	ns
Maximum Data Rate		$V_A = 2\text{ V p-p}$		933		Mbps
DIGITAL SWITCH						
On Resistance	R_{ON}	$V_A = 0\text{ V}$ $I_O = 48\text{ mA}, 15\text{ mA}, 8\text{ mA}$, $T_A = 25^\circ\text{C}$ $I_O = 48\text{ mA}, 15\text{ mA}, 8\text{ mA}$ $V_A = 2.4\text{ V}$ $I_O = 48\text{ mA}, 15\text{ mA}, 8\text{ mA}$, $T_A = 25^\circ\text{C}$ $I_O = 48\text{ mA}, 15\text{ mA}, 8\text{ mA}$		2	4	Ω
					5	Ω
				3	6	Ω
					7	Ω
On-Resistance Matching	ΔR_{ON}	$V_A = 0\text{ V}$, $I_O = 48\text{ mA}, 15\text{ mA}, 8\text{ mA}$		0.15		Ω
POWER REQUIREMENTS						
V_{CC}			3.0		5.5	V
Quiescent Power Supply Current	I_{CC}	Digital inputs = 0 V or V_{CC}		0.001	1	μA
Increase in I_{CC} per Input ^{4, 7}	ΔI_{CC}	$V_{CC} = 5.5\text{ V}$, one input at 3.0 V ; others at V_{CC} or GND			200	μA

¹ Temperature range is: Version B: -40°C to $+85^\circ\text{C}$.

² See Test Circuits section.

³ All typical values are at $T_A = 25^\circ\text{C}$, unless otherwise noted.

⁴ Guaranteed by design, not subject to production test.

⁵ The digital switch contributes no propagation delay other than the RC delay of the typical R_{ON} of the switch and the load capacitance when driven by an ideal voltage source. Because the time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the digital switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

⁶ Propagation delay matching between channels is calculated from on-resistance matching of worst-case channel combinations and load capacitance.

⁷ This current applies to the control pins only and represents the current required to switch internal capacitance at the specified frequency. The A and B ports contribute no significant ac or dc currents as they transition.

ADG3257

$V_{CC} = 3.3 \text{ V} \pm 10\%$, $GND = 0 \text{ V}$. All specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 3.

Parameter ¹	Symbol	Conditions ²	B Version			Unit
			Min	Typ ³	Max	
DC ELECTRICAL CHARACTERISTICS						
Input High Voltage	V_{INH}		2.0			V
Input Low Voltage	V_{INL}		-0.3		+0.8	V
Input Leakage Current	I_i	$0 \leq V_{IN} \leq 3.6 \text{ V}$		± 0.01	± 1	μA
Off State Leakage Current	I_{OZ}	$0 \leq A, B \leq V_{CC}$		± 0.01	± 1	μA
On State Leakage Current	I_{OZ}	$0 \leq A, B \leq V_{CC}$		± 0.01	± 1	μA
Maximum Pass Voltage ⁴	V_P	$V_{IN} = V_{CC} = 3.3 \text{ V}$, $I_o = -5 \mu\text{A}$	2.3	2.6	2.8	V
CAPACITANCE⁴						
A Port Off Capacitance	$C_A \text{ OFF}$	$f = 1 \text{ MHz}$		7		pF
B Port Off Capacitance	$C_B \text{ OFF}$	$f = 1 \text{ MHz}$		5		pF
A, B Port On Capacitance	$C_A, C_B \text{ ON}$	$f = 1 \text{ MHz}$		11		pF
Control Input Capacitance	C_{IN}	$f = 1 \text{ MHz}$		4		pF
SWITCHING CHARACTERISTICS⁴						
Propagation Delay A to B or B to A, t_{PD}	t_{PHL}, t_{PLH} ⁵	$V_A = 0 \text{ V}$, $C_L = 50 \text{ pF}$			0.10	ns
Propagation Delay Matching ⁶		$V_A = 0 \text{ V}$, $C_L = 50 \text{ pF}$		0.01	0.04	ns
Bus Enable Time \overline{BE} to A or B	t_{PZH}, t_{PZL}	$C_L = 50 \text{ pF}$, $R_L = 500 \Omega$	1	5.5	9	ns
Bus Disable Time \overline{BE} to A or B	t_{PHZ}, t_{PLZ}	$C_L = 50 \text{ pF}$, $R_L = 500 \Omega$	1	4.5	8.5	ns
Bus Select Time S to A or B						
Enable	t_{SEL_EN}	$C_L = 50 \text{ pF}$, $R_L = 500 \Omega$		8	12	ns
Disable	t_{SEL_DIS}	$C_L = 50 \text{ pF}$, $R_L = 500 \Omega$		6	9	ns
Maximum Data Rate		$V_A = 2 \text{ V p-p}$		933		Mbps
DIGITAL SWITCH						
On Resistance	R_{ON}	$V_A = 0 \text{ V}$, $I_o = 15 \text{ mA}$, 8 mA , $T_A = 25^\circ\text{C}$	2		4	Ω
		$V_A = 0 \text{ V}$, $I_o = 15 \text{ mA}$, 8 mA			5	Ω
		$V_A = 1 \text{ V}$, $I_o = 15 \text{ mA}$, 8 mA , $T_A = 25^\circ\text{C}$	4		7	Ω
		$V_A = 1 \text{ V}$, $I_o = 15 \text{ mA}$, 8 mA			8	Ω
On-Resistance Matching	ΔR_{ON}	$V_A = 0 \text{ V}$, $I_o = 15 \text{ mA}$, 8 mA		0.2		Ω
POWER REQUIREMENTS						
V_{CC}			3.0		5.5	V
Quiescent Power Supply Current	I_{CC}	Digital inputs = 0 V or V_{CC}		0.001	1	μA
Increase in I_{CC} per Input ^{4,7}	ΔI_{CC}	$V_{CC} = 3.3 \text{ V}$, one input at 3.0 V ; others at V_{CC} or GND			200	μA

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⁶ Propagation delay matching between channels is calculated from on-resistance matching of worst-case channel combinations and load capacitance.

⁷ This current applies to the control pins only and represents the current required to switch internal capacitance at the specified frequency. The A and B ports contribute no significant ac or dc currents as they transition.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 4.

Parameter	Rating
V_{CC} to GND	-0.3 V to +6 V
Digital Inputs to GND	-0.3 V to +6 V
DC Input Voltage	-0.3 V to +6 V
DC Output Current	100 mA
Operating Temperature Range	
Industrial (B Version)	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	150°C
QSOP Package	
θ_{JA} Thermal Impedance	149.97°C/W
Lead Soldering	
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow, Peak Temperature (<20 sec)	220°C
Soldering (Pb-Free)	
Reflow, Peak Temperature	260(+0/-5)°C
Time at Peak Temperature	20 sec to 40 sec

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

ADG3257

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

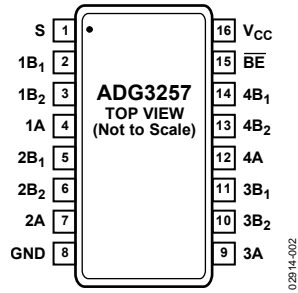


Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	S	Port Select.
2, 3, 5, 6, 10, 11, 13, 14	1B ₁ , 1B ₂ , 2B ₁ , 2B ₂ , 3B ₂ , 3B ₁ , 4B ₂ , 4B ₁	Port B, Inputs or Outputs.
4, 7, 9, 12	1A, 2A, 3A, 4A	Port A, Inputs or Outputs.
8	GND	Negative Power Supply.
15	$\overline{\text{BE}}$	Output Enable (Active Low).
16	V _{CC}	Positive Power Supply.

TYPICAL PERFORMANCE CHARACTERISTICS

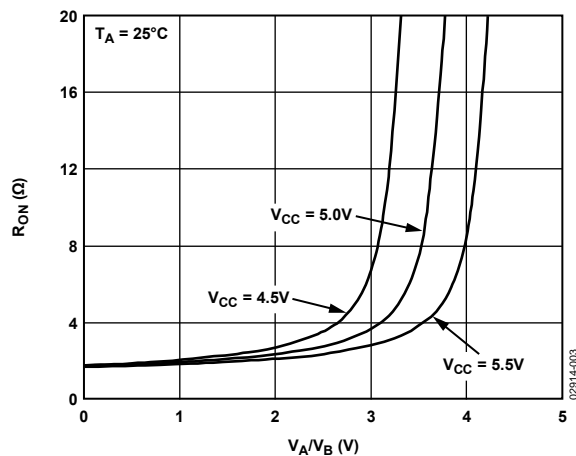


Figure 3. On Resistance vs. Input Voltage

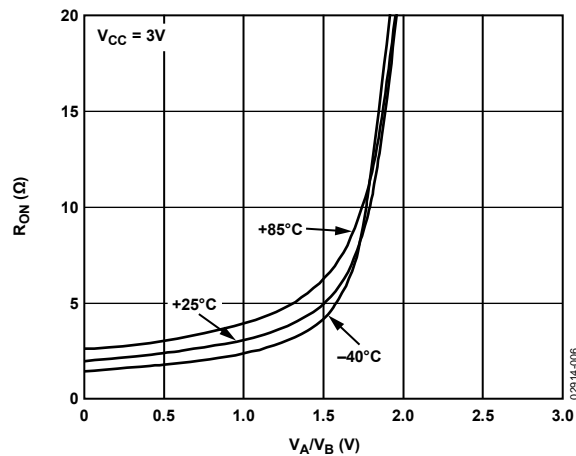


Figure 6. On Resistance vs. Input Voltage for Different Temperatures

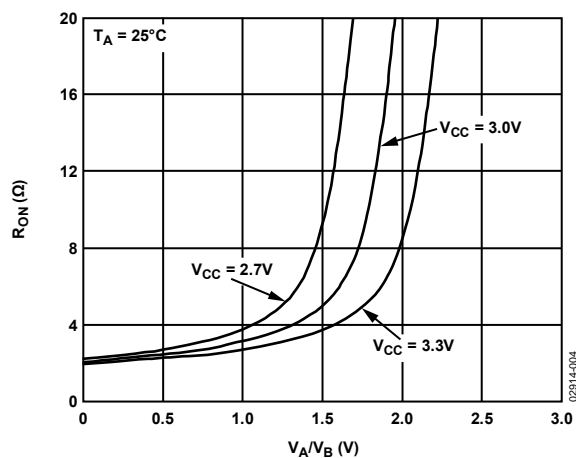


Figure 4. On Resistance vs. Input Voltage

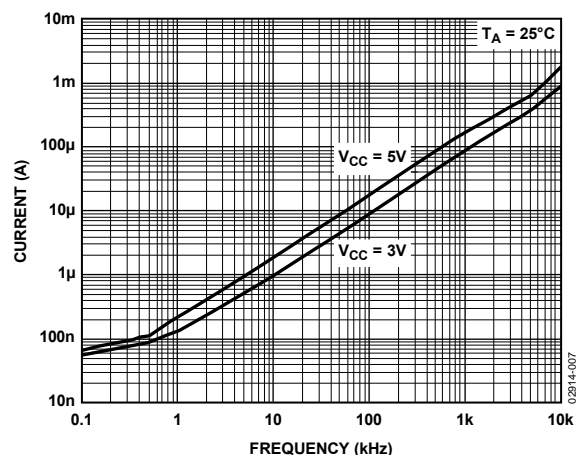


Figure 7. I_{CC} vs. Enable Frequency

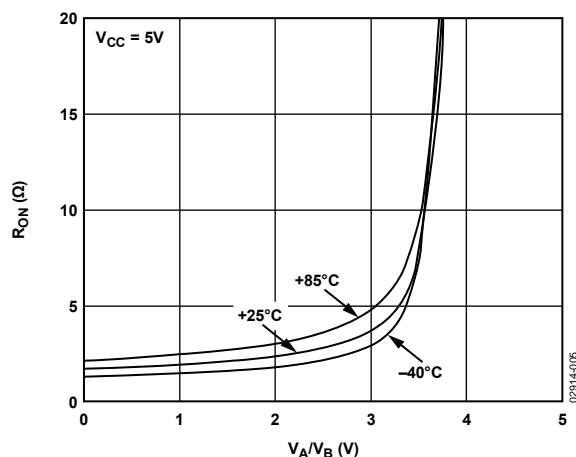


Figure 5. On Resistance vs. Input Voltage for Different Temperatures

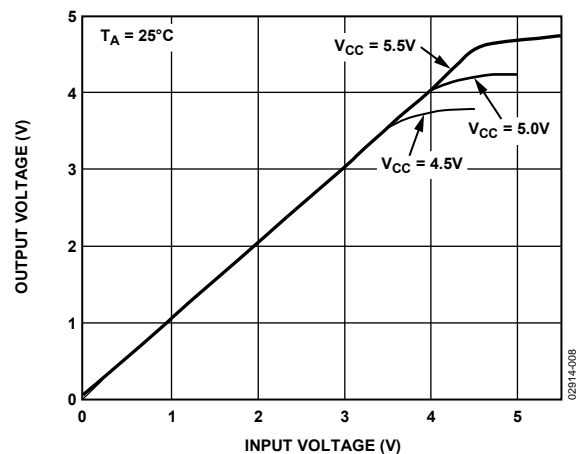


Figure 8. Maximum Pass Voltage

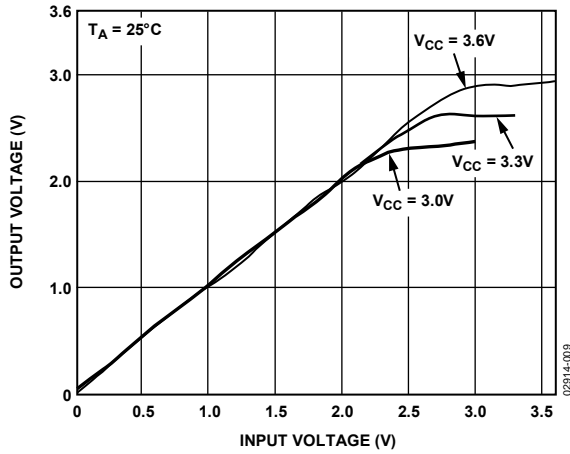


Figure 9. Maximum Pass Voltage

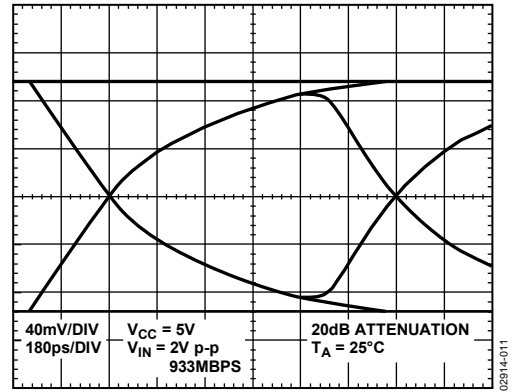


Figure 11. 933 Mbps Eye Diagram

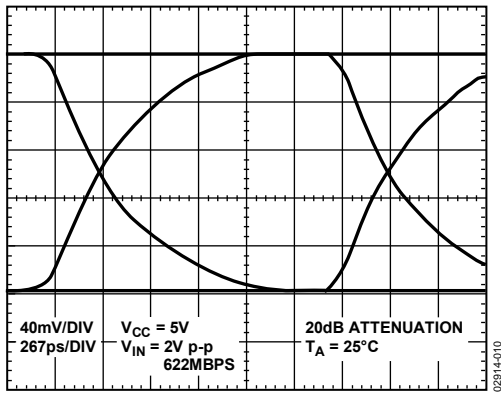
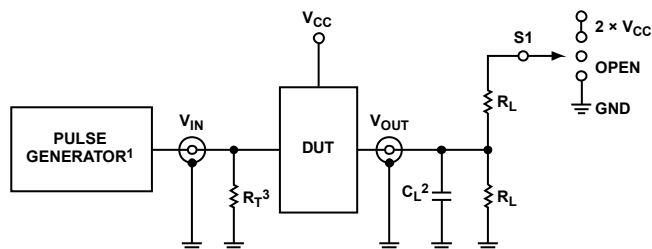


Figure 10. 622 Mbps Eye Diagram

TEST CIRCUITS



- ¹PULSE GENERATOR FOR ALL PULSES: $t_F < 2.5\text{ns}$, $t_R < 2.5\text{ns}$.
- ² C_L = INCLUDES BOARD, STRAY, AND LOAD CAPACITANCES.
- ³ R_T IS THE TERMINATION RESISTOR; SHOULD BE EQUAL TO Z_{OUT} OF THE PULSE GENERATOR.

Figure 12. Load Circuit

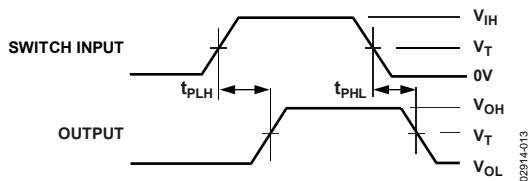


Figure 13. Propagation Delay

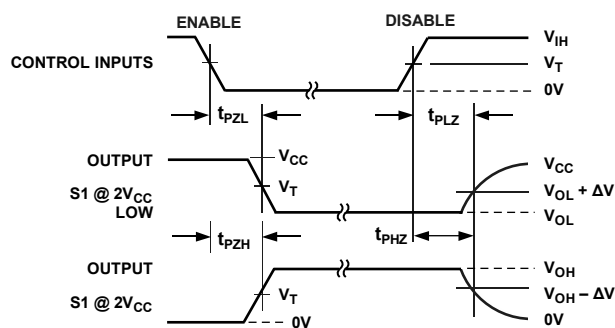


Figure 14. Select, Enable, and Disable Times

Table 6. Switch S1 Condition

Test	S1
t_{PLH} , t_{PHL}	Open
t_{PLZ} , t_{PZL}	$2 \times V_{CC}$
t_{PHZ} , t_{PZH}	GND
t_{SEL}	Open

Table 7. Test Conditions

Symbol	$V_{CC} = 5\text{V} \pm 10\%$	$V_{CC} = 3.3\text{V} \pm 10\%$	Unit
R_L	500	500	Ω
ΔV	300	300	mV
C_L	50	50	pF

02914-012

02914-013

02914-014

APPLICATIONS INFORMATION

MIXED VOLTAGE OPERATION, LEVEL TRANSLATION

Bus switches can be used to provide a solution for mixed voltage systems where interfacing bidirectionally between 5 V and 3.3 V devices is required. To interface between 5 V and 3.3 V buses, an external diode is placed in series with the 5 V power supply as shown in Figure 15.

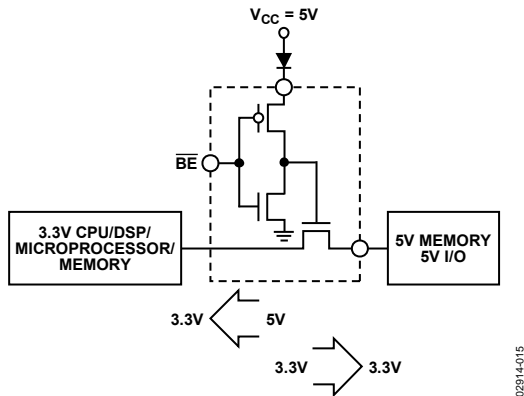


Figure 15. Level Translation Between 5 V and 3.3 V Devices

The diode drops the internal gate voltage down to 4.3 V. The bus switch limits the voltage present on the output to

$$V_{CC} - \text{External Diode Drop} = V_{TH}$$

Therefore, assuming a diode drop of 0.7 V and a V_{TH} of 1 V, the output voltage is limited to 3.3 V with a logic high.

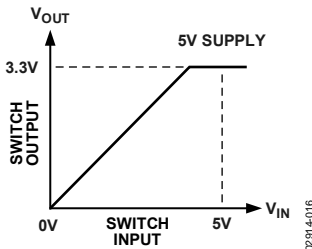


Figure 16. Input Voltage to Output Voltage

Similarly, the device could be used to translate bidirectionally between 3.3 V to 2.5 V systems. In this case, there is no need for an external diode. The internal V_{TH} drop is 1 V, so with a $V_{CC} = 3.3$ V the bus switch limits the output voltage to

$$V_{CC} - 1 \text{ V} = 2.3 \text{ V}$$

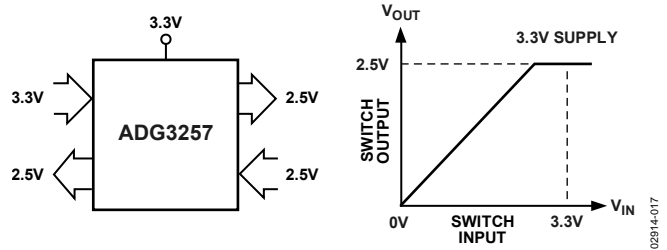


Figure 17. 3.3 V to 2.5 V Level Translation Using the ADG3257 Bus Switch

MEMORY SWITCHING

This quad bus switch may be used to allow switching between different memory banks, thus allowing additional memory and decreasing capacitive loading. Figure 18 illustrates the ADG3257 in such an application.

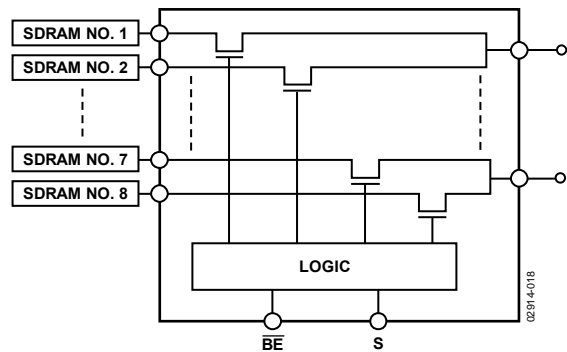
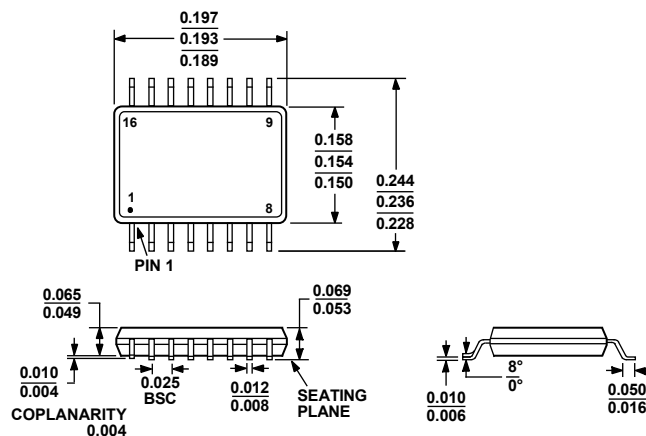


Figure 18. Allows Additional Memory Modules Without Added Drive or Delay

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-137-AB

Figure 19. 16-Lead Shrink Small Outline Package [QSOP]
(RQ-16)

Dimensions shown in inches

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG3257BRQ	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQ-REEL	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQ-REEL7	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQZ ¹	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQZ-REEL ¹	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16
ADG3257BRQZ-REEL7 ¹	-40°C to +85°C	16-Lead Shrink Small Outline Package [QSOP]	RQ-16

¹ Z = RoHS Compliant Part.

ADG3257

NOTES

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